

THE DGD05473 IS <u>NOT</u> RECOMMENDED FOR NEW DESIGNS. PLEASE CONTACT US.



DGD05473

HIGH-FREQUENCY HIGH-SIDE AND LOW-SIDE GATE DRIVER IN V-DFN3030-10

Description

The DGD05473 is a high-frequency gate driver capable of driving nchannel MOSFETs. The floating high-side driver is rated up to 50V.

The DGD05473 logic inputs are compatible with standard TTL and CMOS levels (down to 3.3V) to interface easily with MCUs. UVLO for high-side and low-side will protect a MOSFET with loss of supply. To protect MOSFETs, cross conduction prevention logic prevents the HO and LO outputs from being on at the same time.

Fast and well-matched propagation delays allow a higher switching frequency, enabling a smaller, more compact power switching design, using smaller associated components. To minimize space, an internal bootstrap diode is included. The DGD05473 is offered in the V-DFN3030-10 (Standard) package and operates over an extended -40°C to +125°C temperature range.

Features

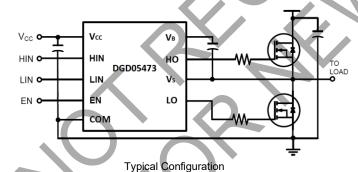
- 50V Floating High-Side Driver
- Drives Two N-Channel MOSFETs in a Half-Bridge Configuration
- 1.5A Source / 2.5A Sink Output Current Capability
- Internal Bootstrap Diode Included
- Undervoltage Lockout for High-Side and Low-Side Drivers
- Delay Matching Maxmimum of 5ns
- Propagation Delay Typical of 20ns
- Logic Input (HIN, LIN, and EN) 3.3V Capability
- Ultra-Low Standby Currents (< 1µA)
- Extended Temperature Range: -40°C to +125°C
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Applications

- DC-DC converters
- Motor control
- Battery-powered hand tools
- eCig devices
- Class-D power amplifiers

Mechanical Data

- Package: V-DFN3030-10
- Package Material: Molded Plastic. "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminals: Finish Matte Tin Finish. Solderable per MIL-STD-202, Method 208 [®]3
- Weight: 0.017 grams (Approximate)



V-DFN3030-10 (Standard)





Top View

Bottom View

Ordering Information (Note 4)

Orderable Part Number	Package Marking Reel Size (inches)		Tape Width (mm)	Packing		
Orderable Part Number	Package	Marking	Reel Size (IllClies)	rape width (min)	Qty.	Carrier
DGD05473FN-7	V-DFN3030-10 (Standard)	DGD05473	7	8	3,000	Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

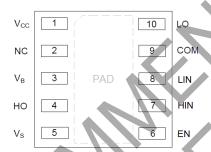


Marking Information



DGD05473 = Product Type Marking Code YY = Year (ex: 25 = 2025) WW = Week (01 to 53)

Pin Assignments



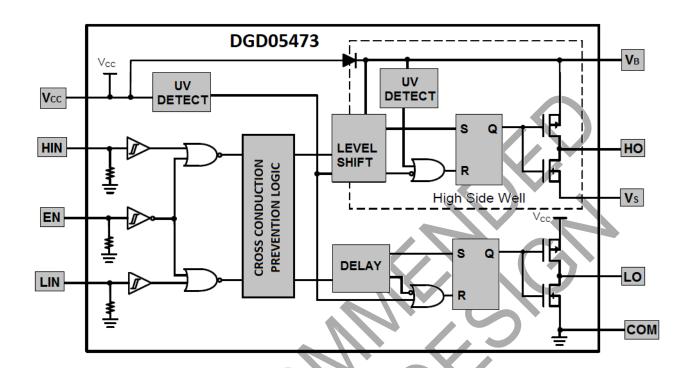
Top View: V-DFN3030-10 (Standard)

Pin Descriptions

Pin Number	Pin Name	Function
1	Vcc	Low-Side and Logic Supply
2	NC	No Connect (No Internal Connection)
3	V_{B}	High-Side Floating Supply
4	НО	High-Side Gate Drive Output
5	Vs	High-Side Floating Supply Return
6	EN	Logic Input Enable, a Logic Low turns off Gate Driver
7	HIN	Logic Input for High-Side Gate Driver, in Phase with HO
8	LIN	Logic Input for Low-Side Gate Driver, in Phase with LO
9	СОМ	Low-Side and Logic Return
10	LO	Low-Side Gate Drive Output
PAD	Substrate	Connect to COM on PCB



Functional Block Diagram





Absolute Maximum Ratings (@ TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
High-Side Floating Positive Supply Voltage	V _B	-0.3 to +60	V
High-Side Floating Negative Supply Voltage	Vs	V _B -14 to V _B +0.3	V
High-Side Floating Output Voltage	Vно	Vs-0.3 to V _B +0.3	V
Offset Supply Voltage Transient	dVs / dt	50	V/ns
Logic and Low-Side Fixed Supply Voltage	Vcc	-0.3 to +14	V
Low-Side Output Voltage	V_{LO}	-0.3 to V _{CC} +0.3	V
Logic-Input Voltage (HIN, LIN and EN)	Vin	-0.3 to V _{CC} +0,3	V
Bootstrap Diode Current (Pulsed < 10µs)	I _{BD}	1	Α

Thermal Characteristics (@ TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation Linear Derating Factor (Note 5)	PD	0.4	W
Thermal Resistance, Junction to Ambient (Note 5)	RθJA	64	°C/W
Thermal Resistance, Junction to Case (Note 5)	Rejc	42	°C/W
Operating Temperature	Tu	+150	
Lead Temperature (Soldering, 10s)	TL	+300	°C
Storage Temperature Range	Тѕтс	-55 to +150	

5. When mounted on a standard JEDEC 2-layer FR-4 board. Note:

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
High-Side Floating Supply	VB	Vs + 4.2	Vs + 14	V
High-Side Floating Supply Offset Voltage	Vs	(Note 6)	50 (Note 7)	V
High-Side Floating Output Voltage	Vно	Vs	V _B	V
Logic and Low-Side Fixed Supply Voltage	Vcc	4.5 (Note 8)	14	V
Low-Side Output Voltage	VLO	0	Vcc	V
Logic-Input Voltage (HIN, LIN and EN)	V _{IN}	0	5	V
Ambient Temperature	TA	-40	+125	°C

Notes:

- 6. Logic operation for V_s of -5V to +50V.
 7. Provided V_B does not exceed absolute maximum rating of 60V.
 8. For operation of V_{CC} = 4.5V to 4.9V, an external bootstrap Schottky diode (0.3V Vfd, 1A) is necessary, see Figure 4. For operation V_{CC} ≥ 4.9V, the external Schottky diode is not required.



DC Electrical Characteristics (V_{CC} = V_{BS} = 12V, COM = V_S = 0, @ T_A = +25°C, unless otherwise specified.) (Note 9)

Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Logic "1" Input Voltage	VIH	2.4	_	_	V	_
Logic "0" Input Voltage	V _{IL}	_	_	0.8	V	_
Enable Logic "1" Input Voltage	VENIH	1.6	_	_	V	_
Enable Logic "0" Input Voltage	VENIL	_	_	0.7	V	_
Input Voltage Hysteresis	VINHYS	_	0.6	_	V	_
Enable Input Voltage Hysteresis	VENINHYS	_	0.1		٧	_
High-Level Output Voltage, VBIAS - VO	Vон	-	0.45	0.6	>	I _{O+} = 100mA
Low-Level Output Voltage, Vo	Vol	_	0.15	0.22	V	I _{O-} = 100mA
Offset Supply Leakage Current	I _{LK}	_	1	5	μA	$V_B = V_S = 60V$
Vcc Shutdown Supply Current	Iccsd	_	0	1	μA	$V_{IN} = 0$ or 5V, $V_{EN} = 0$
Vcc Quiescent Supply Current	Iccq	-	130	200	μA	V _{IN} = 0 or 5V
Vcc Operating Supply Current	Іссор	-	7.3	1	mA	fs = 500kHz, C _L = 1000pF
V _{BS} Quiescent Supply Current	I _{BSQ}	_	40	100	μA	V _{IN} = 0 or 5V
V _{BS} Operating Supply Current	IBSOP	-	7.3		mA 👚	fs = 500kHz, C _L = 1000pF
Logic "1" Input Bias Current	I _{IN+}	-	7—	50	μΑ	V _{IN} = 5V
Logic "0" Input Bias Current	I _{IN-}	_	_	5	μA	$V_{IN} = 0$
Enable Logic "1" Input Bias Current	I _{ENIN+}		43	60	μΑ	VIN = 5V
Enable Logic "0" Input Bias Current	IENIN-	-	0	5	μA	$V_{IN} = 0$
V _{BS} Supply Undervoltage Positive Going Threshold	V _{BSUV+}	3.3	3.8	4.4	>	
V _{BS} Supply Undervoltage Negative Going Threshold	VBSUV-	2.9	3.3	3.9	٧	_
Vcc Supply Undervoltage Positive Going Threshold	Vccuv+	3.3	3.8	4.4	٧	_
V _{CC} Supply Undervoltage Negative Going Threshold	Vccuv-	2.9	3.3	3.9	V	_
Output High Short-Circuit Pulsed Current	lo+	1.0	1.5	-/	Α	Vo = 0, Pw ≤ 10μs
Output Low Short-Circuit Pulsed Current	lo-	1.9	2.5	Y _	Α	V _O = 15V, P _W ≤ 10μs
Forward Voltage of Bootstrap Diode	V _{F1}	_	0.67	-	V	I _F = 100μA
Forward Voltage of Bootstrap Diode	VF2	_	1.2	_	V	I _F = 100mA

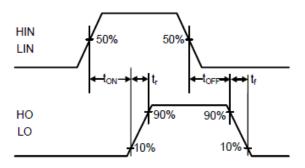
Note: 9. The V_{IN} and I_{IN} parameters are applicable to the logic pins: HIN, LIN and EN. The V_O and I_O parameters are applicable to the respective output pins: HO and LO.

AC Electrical Characteristics (V_{CC} = V_{BS} = 12V, COM = V_S = 0, C_L = 1000pF, @ T_A = +25°C, unless otherwise specified.)

Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Turn-On Propagation Delay	ton	_	20	35	ns	_
Turn-Off Propagation Delay	toff		23	56	ns	Vs = 50V
Delay Matching, HO & LO Turn-On	t _{DM}		_	5	ns	_
Turn-On Rise Time	tr	_	16	30	ns	_
Turn-Off Fall Time	tf	_	12	25	ns	_



Timing Waveforms



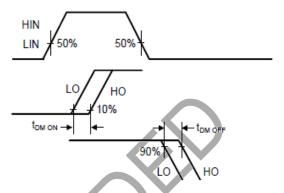


Figure 1. Switching Time Waveform Definitions

Figure 2. Delay Matching Waveform Definitions

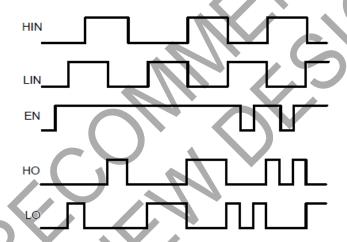


Figure 3. Input / Output Timing Diagram

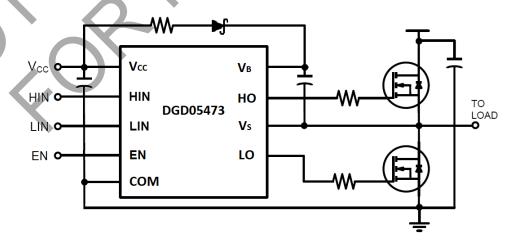


Figure 4. Typical application necessary for $V_{CC}=4.5V$ to 4.9V operation. For $V_{CC}\geq4.9V$, the bootstrap Schottky diode (0.3V Voltage drop, 1A) and resistor are not required.



Typical Performance Characteristics (V_{CC} = 12V, @ T_A = +25°C, unless otherwise specified.)

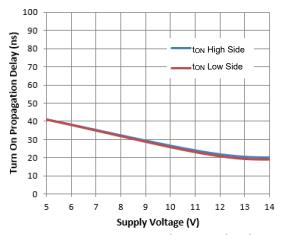


Figure 5. Turn-on Propagation Delay vs. Supply Voltage

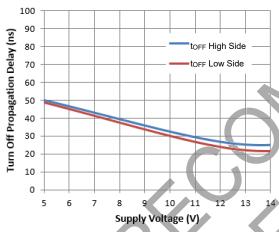


Figure 7. Turn-off Propagation Delay vs. Supply Voltage

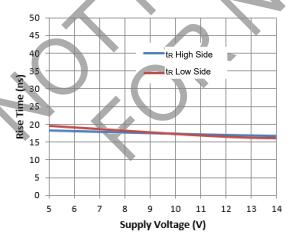


Figure 9. Rise Time vs. Supply Voltage

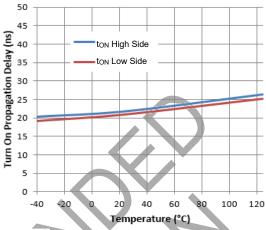


Figure 6. Turn-on Propagation Delay vs. Temperature

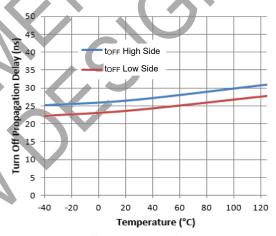


Figure 8. Turn-off Propagation Delay vs. Temperature

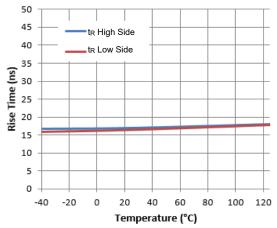


Figure 10. Rise Time vs. Temperature



Typical Performance Characteristics (V_{CC} = 12V, @ T_A = +25°C, unless otherwise specified.) (continued)

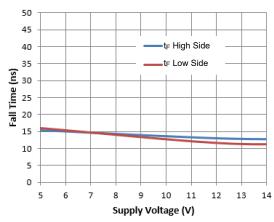


Figure 11. Fall Time vs. Supply Voltage

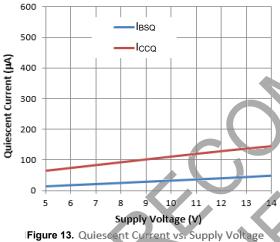


Figure 13. Quiescent Current vs. Supply Voltage

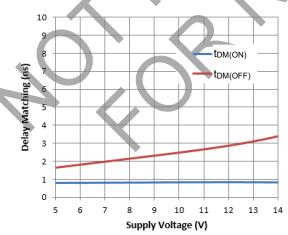


Figure 15. Delay Matching vs. Supply Voltage

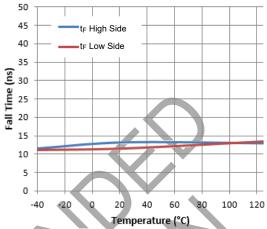


Figure 12. Fall Time vs. Temperature

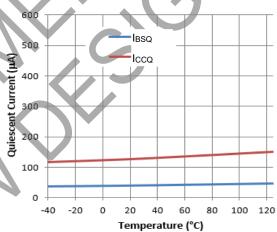


Figure 14. Quiescent Current vs. Temperature

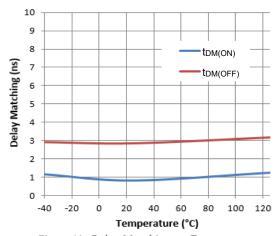


Figure 16. Delay Matching vs. Temperature



Typical Performance Characteristics (V_{CC} = 12V, @ T_A = +25°C, unless otherwise specified.) (continued)

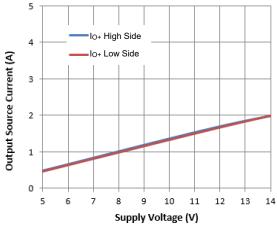


Figure 17. Output Source Current vs. Supply Voltage

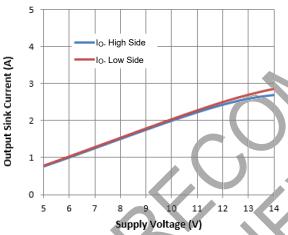


Figure 19. Output Sink Current Vs. Supply Voltage

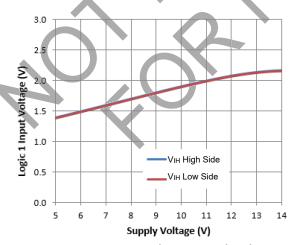


Figure 21. Logic 1 Input Voltage vs. Supply Voltage

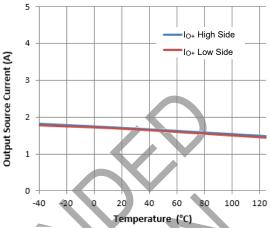


Figure 18. Output Source Current vs. Temperature

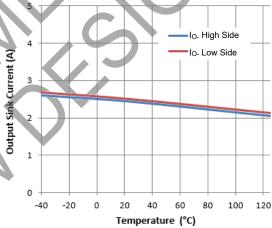


Figure 20. Output Sink Current vs. Temperature

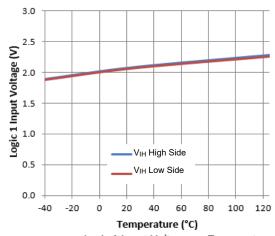


Figure 22. Logic 1 Input Voltage vs. Temperature



$\textbf{Typical Performance Characteristics} \ (V_{CC} = 12V, @ T_A = +25^{\circ}C, \text{ unless otherwise specified.}) \ (\text{continued})$

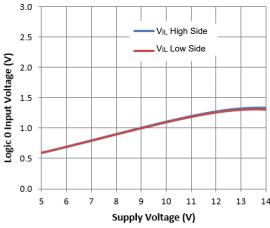


Figure 23. Logic 0 Input Voltage vs. Supply Voltage

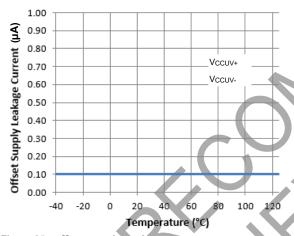


Figure 25. Offset Supply Leakage Current vs. Temperature

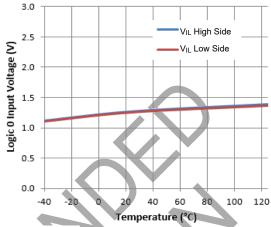


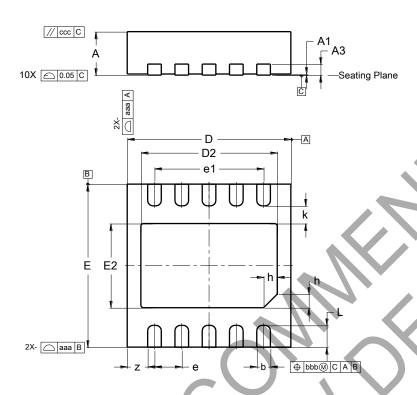
Figure 24. Logic 0 Input Voltage vs. Temperature



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

V-DFN3030-10 (Standard)

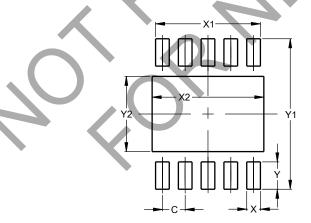


V-DFN3030-10							
	(Standard)						
Dim	Min						
Α	0.75	0.85	0.80				
A1	0.00	0.05	0.02				
A3	i	1	0.203				
b	0.18	0.30	0.25				
D	2.90	3.10	3.00				
D2	2.40	2.60	2.50				
е	0.50BSC						
e1	(2.00BS	SC .				
E	2.90	3.10	3.00				
E2	1.45	1.65	1.55				
h	0.20	0.30	0.25				
k) I	ı	0.325				
1	0.30	0.50	0.40				
z			0.325				
aaa	0.250						
bbb	0.100						
CCC	0.050						
All Dimensions in mm							

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

V-DFN3030-10 (Standard)



Dimensions	Value (in mm)		
С	0.500		
Х	0.300		
X1	2.300		
X2	2.600		
Y	0.600		
Y1	3.300		
Y2	1.650		



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